

Enable High Flux and Cost Efficient System

## Z Power Chip on board – ZC series SDW\*2F1C (SDW02F1C, SDW82F1C, SDW92F1C)











### **Product Brief**

### **Description**

- The ZC series are LED arrays which provide High Flux and High Efficacy.
- It is especially designed for easy assembly of lighting fixtures by eliminating reflow soldering process.
- It's thermal management is better than other power LED solutions with wide Metal area.
- ZC series are ideal light sources for General Lighting applications including Replacement Lamps, Industrial & Commercial Lightings and other high Lumen required applications.

#### **Features and Benefits**

- Size 19mm \* 19 mm
- Power dissipation 12.6 ~ 27.6W
- Wide CCT range with CRI70~90
- Forward current typ 35.9V
- Maximum Current 690mA
- MacAdam 3-step binning
- Uniformed Shadow
- · Excellent Thermal management
- RoHS compliant

#### **Key Applications**

- Commercial Downlight
- Industrial Low bay lighting
- Residential
- Replacement lamps Bulb, PAR

**Table 1. Product Selection Table** 

сст [к]							
Color	Min.	Тур.	Max.				
Cool White	4,700	-	6,000				
Neutral White	3,700	-	4,700				
Cool White	4,700	-	6,000				
Neutral White	3,700	-	4,700				
Warm White	2,600	-	3,700				
Neutral White	3,700	-	4,200				
Warm White	2,600	-	3,700				
	Cool White  Neutral White  Cool White  Neutral White  Warm White  Neutral White	Color         Min.           Cool White         4,700           Neutral White         3,700           Cool White         4,700           Neutral White         3,700           Warm White         2,600           Neutral White         3,700	Color         Min.         Typ.           Cool White         4,700         -           Neutral White         3,700         -           Cool White         4,700         -           Neutral White         3,700         -           Warm White         2,600         -           Neutral White         3,700         -				



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### **Performance Characteristics**

Table 2. Electro Optical Characteristics, T<sub>i</sub>=25°C

Part Number	CCT (K) <sup>[1]</sup>	Typical Lumi Ф <sub>V</sub> <sup>[3</sup>	inous Flux <sup>[2]</sup> ,	Typical Forw V <sub>F</sub> <sup>[4</sup>	vard Voltage,	CRI <sup>[5]</sup> , R <sub>a</sub>	Viewing Angle (degrees) 20 ½
	Тур.	350mA	690mA*	350mA	690mA*	Min.	Тур.
	5600	1908	3407	35.9	38.2	70	120
CDW00E4C	5000	1918	3423	35.9	38.2	70	120
SDW02F1C	4500	1958	3496	35.9	38.2	70	120
	4000	1971	3518	35.9	38.2	70	120
	5600	1868	3328	35.9	38.2	80	120
	5000	1902	3396	35.9	38.2	80	120
SDW82F1C	4000	1800	3132	35.9	38.2	80	120
SDW62FTC	3500	1744	3034	35.9	38.2	80	120
	3000	1727	3074	35.9	38.2	80	120
	2700	1684	2994	35.9	38.2	80	120
	4000	1530	2670	35.9	38.2	90	120
SDW92F1C	3500	1505	2626	35.9	38.2	90	120
5DW92F1C	3000	1475	2581	35.9	38.2	90	120
	2700	1353	2367	35.9	38.2	90	120

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate: ±0.005, CCT ±5% tolerance.
- (2) Seoul Semiconductor maintains a tolerance of  $\pm 7\%$  on flux and power measurements.
- (3)  $\Phi_{V}$  is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is  $\pm 3\%$  on forward voltage measurements.
- (5) Tolerance is  $\pm 2$  on CRI measurements.

<sup>\*</sup> No values are provided by real measurement. Only for reference purpose.

### **Performance Characteristics**

Table 3. Electro Optical Characteristics, T<sub>i</sub>=85°C

Part Number	CCT (K) [1]	Typical Luminous Flux $^{[2]}$ , $\Phi_{v}^{[3]}$ (lm)	Typical Forward Voltage, V <sub>F</sub> <sup>[4]</sup> (V)
	Тур.	350mA *	350mA *
	5600	1727	34.4
CDW00E4C	5000	1736	34.4
SDW02F1C	4500	1772	34.4
	4000	1784	34.4
	5600	1681	34.4
	5000	1712	34.4
SDW82F1C	4000	1620	34.4
SDW82F1C	3500	1570	34.4
	3000	1554	34.4
	2700	1515	34.4
	4000	1339	34.4
CDW00E4C	3500	1317	34.4
SDW92F1C	3000	1291	34.4
	2700	1184	34.4

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate:  $\pm 0.005$ , CCT  $\pm 5\%$  tolerance.
- (2) Seoul Semiconductor maintains a tolerance of  $\pm 7\%$  on flux and power measurements.
- (3)  $\Phi_{V}$  is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is  $\pm 3\%$  on forward voltage measurements.
- (5) Tolerance is  $\pm 2$  on CRI measurements.

<sup>\*</sup> No values are provided by real measurement. Only for reference purpose.

### **Performance Characteristics**

Table 4. Absolute Maximum Characteristics, T<sub>i</sub>=25°C

Parameter	O		Value		11
Parameter	Symbol	Min.	Тур.	Max.	Unit
Forward Current	I <sub>F</sub>	-	0.35	0.69	Α
Power Dissipation	$P_d$	-	12.6	27.6	W
Junction Temperature	Tj	-	-	140	°C
Operating Temperature	T <sub>opr</sub>	-40	-	85	°C
Surface Temperature	Ts	-	-	100	°C
Storage Temperature	$T_{stg}$	-40	-	100	°C
Thermal resistance (J to S) [1]	Rth <sub>JS</sub>	-	0.9	-	K/W
ESD Sensitivity(HBM)	-		Class 3A JES	SD22-A114-E	

- (1) Thermal resistance :  $Rth_{JS}$  (Junction / solder)
- LED's properties might be different from suggested values like above and below tables if
  operation condition will be exceeded our parameter range. Care is to be taken that power
  dissipation does not exceed the absolute maximum rating of the product.
- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.
- All measurements were made under the standardized environment of Seoul Semiconductor.

Fig 1. Color Spectrum, T<sub>i</sub>=25°C, I<sub>F</sub>=350mA (CRI70)

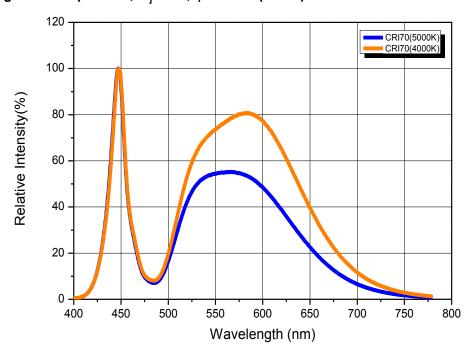


Fig 2. Color Spectrum, T<sub>i</sub>=25°C, I<sub>F</sub>=350mA (CRI80)

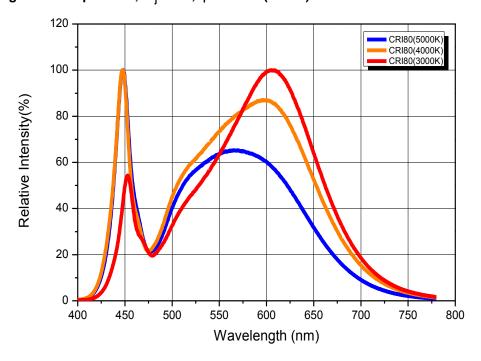


Fig 3. Color Spectrum, T<sub>i</sub>=25°C, I<sub>F</sub>=350mA (CRI90)

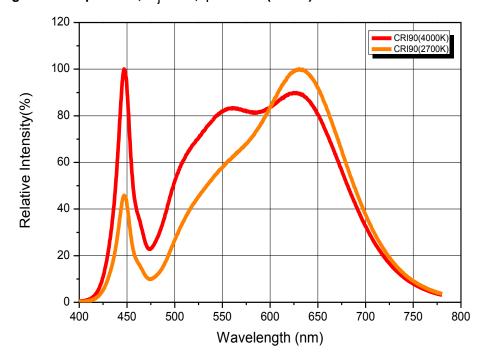


Fig 4. Radiant pattern, T<sub>j</sub>=25°C, I<sub>F</sub>=350mA

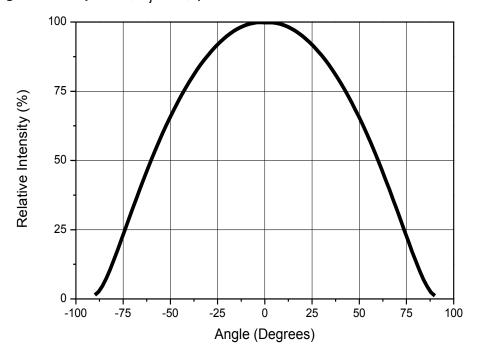


Fig 5. Forward Voltage vs. Forward Current, T<sub>i</sub>=25°C

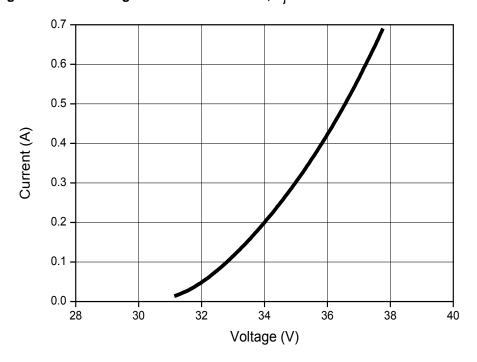


Fig 6. Forward Current vs. Relative Luminous Flux, T<sub>i</sub>=25°C

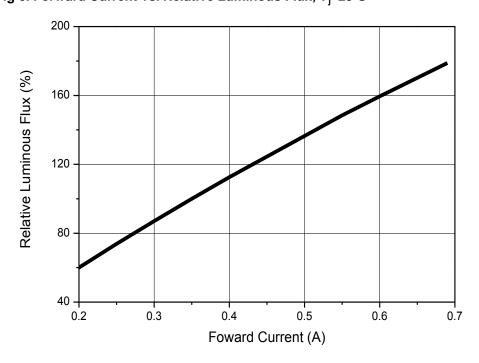


Fig 7. Junction Temperature vs. Relative Light Output, I<sub>F</sub>=350mA

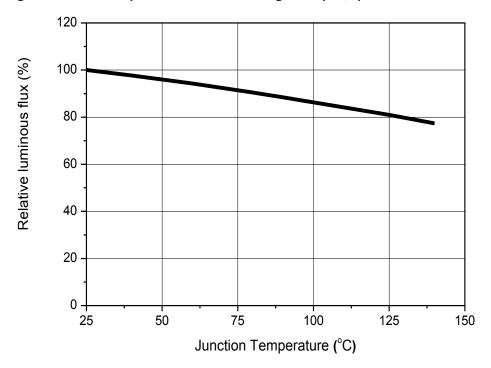


Fig 8. Junction Temperature vs. Forward Voltage, I<sub>F</sub>=350mA

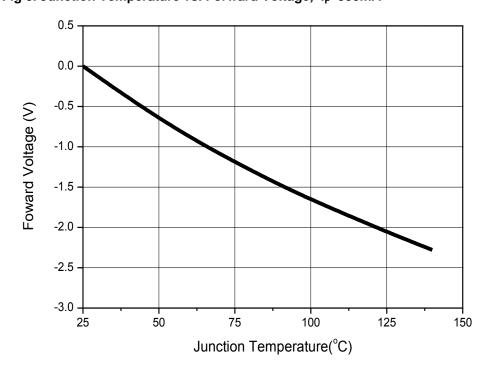


Fig 9. Junction Temperature vs. CIE X, Y Shift, I<sub>F</sub>=350mA (CRI70)

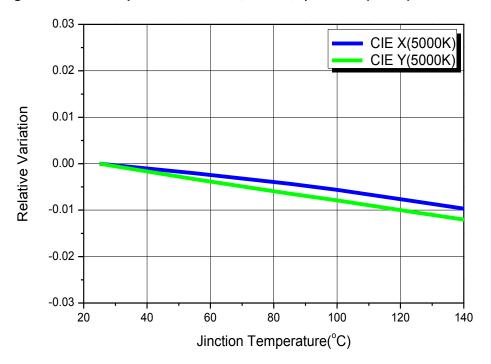


Fig 10. Junction Temperature vs. CIE X, Y Shift, I<sub>F</sub>=350mA (CRI90)

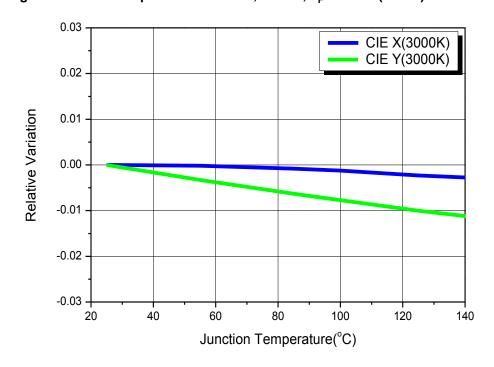
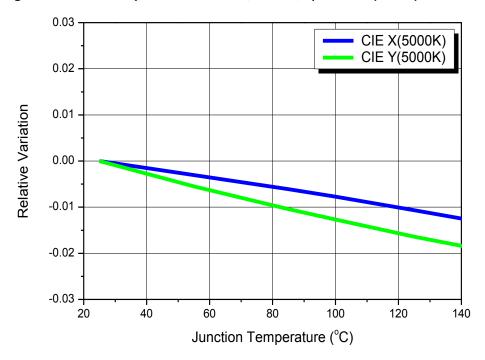


Fig 11. Junction Temperature vs. CIE X, Y Shift, I<sub>E</sub>=350mA (CRI80)



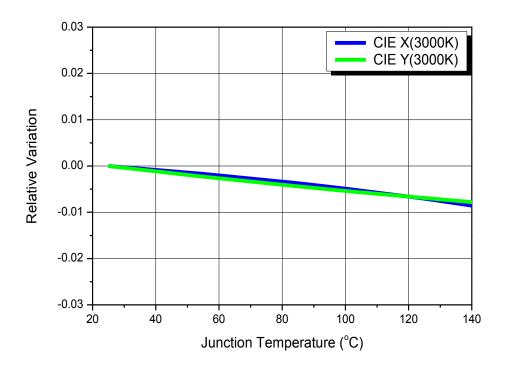
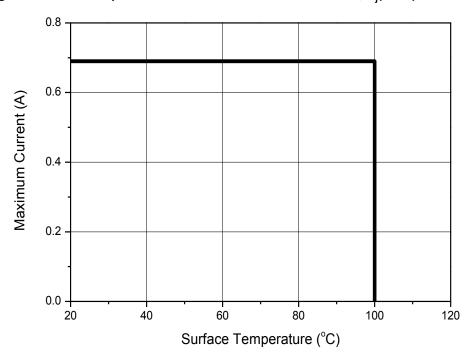


Fig 12. Surface Temperature vs. Maximum Forward Current, T<sub>i</sub>(max.)=140°C



## **Color Bin Structure**

Table 7. Bin Code description

Part Number		nous Flux (I I <sub>F</sub> = 350mA	m)	Color Chromaticity Coordinate	Typical Forward Voltage (V <sub>1</sub> ) @ I <sub>F</sub> = 350mA			
	Bin Code	Min.	Max.	@ I <sub>F</sub> = 350mA	Bin Code	Min.	Max.	
	G2	1600	1800		E	34.0	38.0	
SDW02F1C	H1	1800	2400	Refer to page.15~18	F			
	H2	2400	2900	, 3		38.0	40.0	
	F2	1250	1400		E	34.0	38.0	
SDW82F1C	G1	1400	1600	Refer to		34.0	30.0	
SDW62F1C	G2	1600	1800	page.15~18	F	22.0	40.0	
	H1	1800	2400		Г	38.0	40.0	
	F1	1100	1250	Defeate	E	34	38	
SDW92F1C	F2	1250	1400	Refer to page.15~18				
	G1	1400	1600		F	38	40	

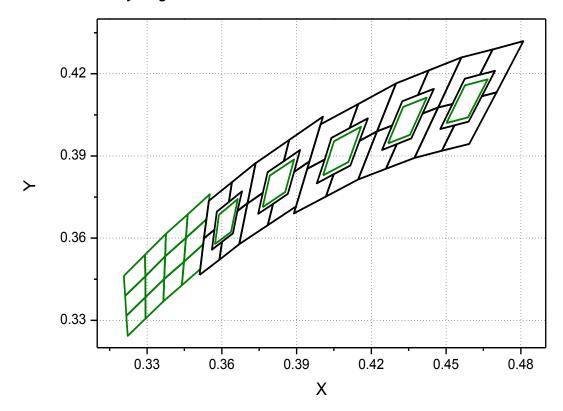
Table 8. Ordering Information(Bin Code)

Available ranks

Part Number	сст	CIE		LF rank	ς.		VF	rank
	5300~6000K	В	G2	H1	Н	2	Е	F
CDW00E4C	4700~5300K	С	G2	H1	Н	2	Е	F
SDW02F1C	4200~4700K	D	G2	H1	Н	2	Е	F
	3700~4200K	Е	G2	H1	Н	2	Е	F
	5300~6000K	В	F2	G1	G2	H1	E	F
	4700~5300K	С	F2	G1	G2	H1	E	F
CDW00E4C	3700~4200K	Е	F2	G1	G2	H1	Е	F
SDW82F1C	3200~3700K	F	F2	G1	G2	H1	E	F
	2900~3700K	G	F2	G1	G2	H1	Е	F
	2600~2900K	Н	F2	G1	G2	H1	Е	F
	3700~4200K	Е	F1	F2	G	1	E	F
CDW00E4C	3200~3700K	F	F1	F2	G	1	E	F
SDW92F1C	2900~3200K	G	F1	F2	G	1	E	F
	2600~2900K	Н	F1	F2	G	1	E	F

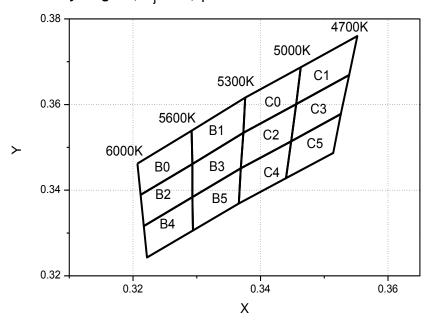
## **Color Bin Structure**

### **CIE Chromaticity Diagram**



## **Color Bin Structure**

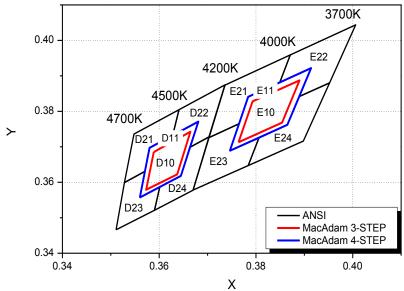
## CIE Chromaticity Diagram, $T_j=25$ °C, $I_F=350$ mA



В	0	В	1	В	2
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3207	0.3462	0.3292	0.3539	0.3212	0.3389
0.3212	0.3389	0.3293	0.3461	0.3217	0.3316
0.3293	0.3461	0.3373	0.3534	0.3293	0.3384
0.3292	0.3539	0.3376	0.3616	0.3293	0.3461
В	3	В	4	В	5
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3293	0.3461	0.3217	0.3316	0.3293	0.3384
0.3293	0.3384	0.3222	0.3243	0.3294	0.3306
0.3369	0.3451	0.3294	0.3306	0.3366	0.3369
0.3373	0.3534	0.3293	0.3384	0.3369	0.3451
С	0	C	1	С	2
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3376	0.3616	0.3463	0.3687	0.3373	0.3534
0.3373	0.3534	0.3456	0.3601	0.3369	0.3451
0.3456	0.3601	0.3539	0.3669	0.3448	0.3514
0.3463	0.3687	0.3552	0.3760	0.3456	0.3601
С	3	C	4	С	5
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3456	0.3601	0.3369	0.3451	0.3448	0.3514
0.3448	0.3514	0.3366	0.3369	0.3440	0.3428
0.3526	0.3578	0.3440	0.3428	0.3514	0.3487
0.3539	0.3669	0.3448	0.3514	0.3526	0.3578

## **Color Bin Structure**

## CIE Chromaticity Diagram, $T_j=25$ °C, $I_F=350$ mA

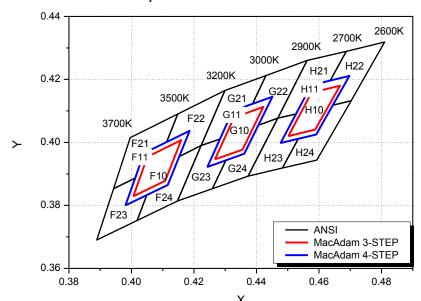


	3-S	ТЕР		4-STEP					
D10		E10		D <sup>,</sup>	11	E11			
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y		
0.3589	0.3685	0.3764	0.3713	0.3560	0.3557	0.3746	0.3689		
0.3665	0.3742	0.3793	0.3828	0.3580	0.3697	0.3784	0.3841		
0.3637	0.3622	0.3890	0.3887	0.3681	0.3771	0.3914	0.3922		
0.3573	0.3579	0.3854	0.3768	0.3645	0.3618	0.3865	0.3762		

	ANSI											
D	21	D	22	D:	23	D24						
CIE x	CIE y											
0.3528	0.3599	0.3628	0.3732	0.3601	0.3587	0.3511	0.3466					
0.3548	0.3736	0.3641	0.3805	0.3645	0.3618	0.3528	0.3599					
0.3641	0.3805	0.3736	0.3874	0.3663	0.3699	0.3570	0.3631					
0.3628	0.3732	0.3703	0.3728	0.3703	0.3728	0.3560	0.3558					
0.3580	0.3697	0.3663	0.3699	0.3670	0.3578	0.3601	0.3587					
0.3570	0.3631	0.3681	0.3771	0.3590	0.3521	0.3590	0.3521					
E	21	E	22	E	23	E24						
CIE x	CIE y											
0.3703	0.3726	0.3890	0.3842	0.3670	0.3578	0.3784	0.3647					
0.3736	0.3874	0.3914	0.3922	0.3703	0.3726	0.3806	0.3725					
0.3871	0.3959	0.3849	0.3881	0.3765	0.3765	0.3865	0.3762					
0.3849	0.3881	0.3871	0.3959	0.3746	0.3689	0.3890	0.3842					
0.3784	0.3841	0.4006	0.4044	0.3806	0.3725	0.3952	0.3880					
0.3765	0.3765	0.3952	0.3880	0.3784	0.3647	0.3898	0.3716					

## **Color Bin Structure**

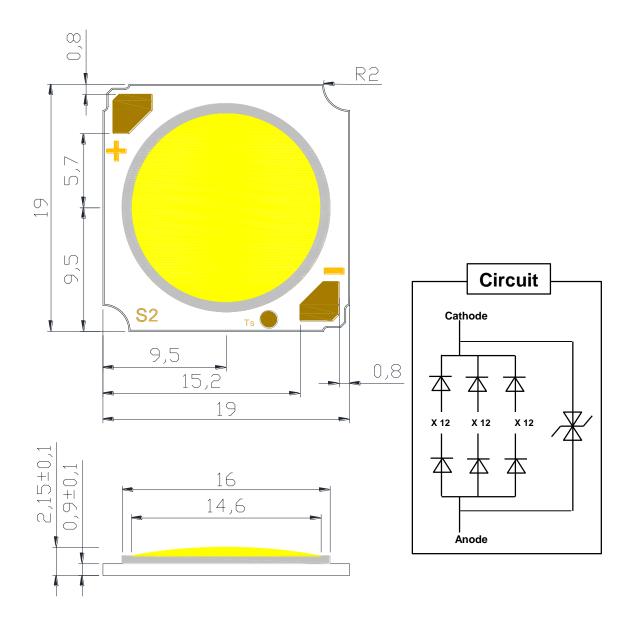
### CIE Chromaticity Diagram, $T_j=25$ °C, $I_F=350$ mA



						^					
		3-S	TEP					4-S	TEP		
F10		G10		H10		F11		G11		H11	
CIE x	CIE y										
0.4006	0.3829	0.4267	0.3946	0.4502	0.4020	0.3981	0.3800	0.4243	0.3922	0.4477	0.3998
0.4051	0.3954	0.4328	0.4079	0.4576	0.4158	0.4040	0.3966	0.4324	0.4100	0.4575	0.4182
0.4159	0.4007	0.4422	0.4113	0.4667	0.4180	0.4186	0.4037	0.4451	0.4145	0.4697	0.4211
0.4108	0.3878	0.4355	0.3977	0.4588	0.4041	0.4116	0.3865	0.4361	0.3964	0.4591	0.4025

0.4108	0.3878	0.4355	0.3977	0.4588	0.4041	0.4116	0.3865	0.4361	0.3964	0.4591	0.4025
					1A	NSI					
	F21			F22			F23			F24	
CIE x	(	CIE y	CIE x		CIE y	CIE x		CIE y	CIE x		CIE y
0.4148	3 0	0.4090	0.4013	3 (	0.3887	0.4223	3	0.3990	0.4299	9	0.4165
0.3996	5 C	0.4015	0.3943	3 (	0.3853	0.4153	3	0.3955	0.4148	3	0.4090
0.3943	3 0	0.3853	0.3889	9 (	0.3690	0.4116	;	0.3865	0.4113	3	0.4002
0.4013	3 0	).3887	0.4018	3 (	0.3752	0.4049	)	0.3833	0.4186	3	0.4037
0.4040	) (	0.3966	0.4049	9 (	0.3833	0.4018	3	0.3752	0.4153	3	0.3955
0.4113	3 0	0.4002	0.398	1 (	0.3800	0.4147	,	0.3814	0.4223	3	0.3990
	G21			G22			G23		G24		
CIE x		CIE y									
0.4223	3 0	0.3990	0.4406	6 (	0.4055	0.4147	•	0.3814	0.4259	9	0.3853
0.4299	9 0	).4165	0.445	1 (	0.4145	0.4223	3	0.3990	0.4302	2	0.3943
0.4430	) (	).4212	0.4387	7 (	).4122	0.4284	ļ	0.4011	0.436	1	0.3964
0.4387	7 C	).4122	0.4430	) (	0.4212	0.4243	3	0.3922	0.4406	3	0.4055
0.4324	4 C	0.4100	0.4562	2 (	0.4260	0.4302	2	0.3943	0.4468	3	0.4077
0.4284	4 C	0.4011	0.4468	3 (	0.4077	0.4259	)	0.3853	0.4373	3	0.3893
	H21			H22			H23			H24	
CIE x		CIE y									
0.4468	3 0	).4077	0.464	4 (	0.4118	0.4373	3	0.3893	0.4483	3	0.3919
0.4562	2 0	).4260	0.4697	7 (	0.4211	0.4468	3	0.4077	0.4534	1	0.4012
0.4687	7 0	).4289	0.4636	6 (	).4197	0.4526	3	0.4090	0.459	1	0.4025
0.4636	6 0	).4197	0.4687	7 (	0.4289	0.4477	'	0.3998	0.464	1	0.4118
0.4575	5 0	).4182	0.4810	) (	0.4319	0.4534		0.4012	0.4703	3	0.4132
0.4526	6 0	0.4090	0.4703	3 (	0.4132	0.4483	3	0.3919	0.4593	3	0.3944

## **Mechanical Dimensions**



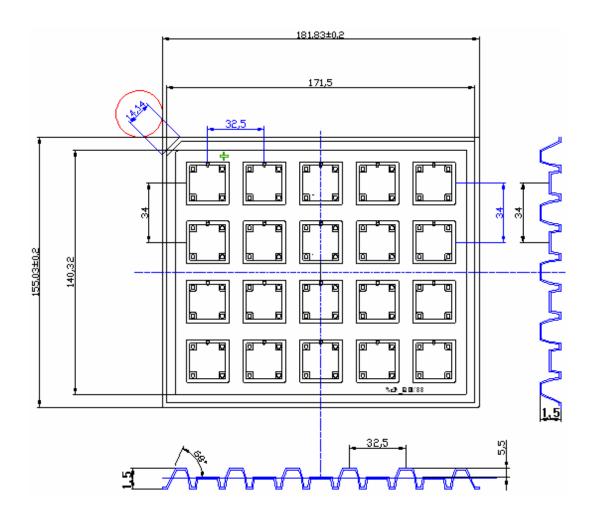
### Notes:

(1) All dimensions are in millimeters.

(2) Scale: none

(3) Undefined tolerance is  $\pm 0.2$ mm

# **Packaging Specification**



#### Notes:

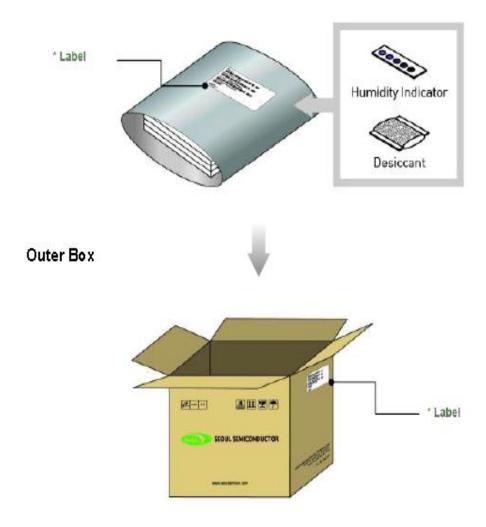
(1) Quantity: 20pcs/Tray

(2) All dimensions are in millimeters (tolerance :  $\pm 0.3)\,$ 

(3) Scale none

# **Packaging Specification**

### Aluminum Bag



- (1) Heat Sealed after packing (Use Zipper Bag)
- (2) Quantity: 3Tray(60pcs)/Bag

## **Product Nomenclature**

Table 5. Part Numbering System :  $X_1X_2X_3X_4X_5X_6X_7X_8$ 

Part Number Code	Description	Part Number	Value
<b>X</b> <sub>1</sub>	Company	S	
X <sub>2</sub>	Package series	D	
$X_3X_4$	Color Specification	W0	CRI 70
		W8	CRI 80
		W9	CRI 90
X <sub>5</sub>	Series number	2	
X <sub>6</sub>	Lens type	F	Flat
X <sub>7</sub>	PCB type	1	PCB
X <sub>8</sub>	Revision number	С	New COB type

Table 6. Lot Numbering System :  $Y_1Y_2Y_3Y_4Y_5Y_6$   $Y_7Y_8Y_9Y_{10}$  –  $Y_{11}Y_{12}Y_{13}Y_{14}Y_{15}Y_{16}Y_{17}$ 

Lot Number Code	Description	
$Y_1Y_2Y_3Y_4Y_5$	Date of box packing	
$Y_6Y_7Y_8Y_9Y_{10}$	Date of label order	
$Y_{11}Y_{12}Y_{13}Y_{14}Y_{15}Y_{16}Y_{17}$	Item code	

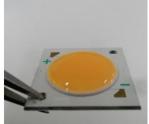
## **Handling of Silicone Resin for LEDs**

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.





- (3) Silicone differs from materials conventionally used for the manufacturing of LEDs.
  These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust. As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of wire.
- (4) Seoul Semiconductor suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not
  - recommended. Ultrasonic cleaning may cause damage to the LED.
- (5) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.
- (6) Avoid leaving fingerprints on silicone resin parts.

### **Precaution for Use**

(1) Storage

To avoid the moisture penetration, we recommend storing Power LEDs in a dry box with a desiccant

- (2) For manual soldering
  - Seoul Semiconductor recommends the soldering condition
  - (ZC series product is not adaptable to reflow process)
  - a. Use lead-free soldering
  - Soldering should be implemented using a soldering equipment at temperature lower than 350°C.
  - c. Before proceeding the next step, product temperature must be stabilized at room temperature.
- (3) Components should not be mounted on warped (non coplanar) portion of PCB.
- (4) Radioactive exposure is not considered for the products listed here in.
- (5) It is dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.
- (6) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.
- (7) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.
- (8) The appearance and specifications of the product may be modified for improvement without notice.
- (9) Long time exposure of sun light or occasional UV exposure will cause silicone discoloration.
- (10) Attaching LEDs, do not use adhesive that outgas organic vapor.
- (11) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.
- (12) Please do not touch any of the circuit board, components or terminals with bare hands or metal while circuit is electrically active.

### **Precaution for Use**

(13) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.

(14) LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

#### I . ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

#### Environmental controls:

- Humidity control (ESD gets worse in a dry environment)



### **Precaution for Use**

#### 

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
  (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.
- III. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:
  - A surge protection circuit
  - An appropriately rated over voltage protection device
  - A current limiting device



## **Company Information**

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#### **Company Information**

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

#### **Legal Disclaimer**

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